L Number	Hits	Search Text	DB	Time stamp
_	242	(257/253).CCLS.	USPAT;	2004/08/06 14:31
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	1
			IBM_TDB	
-	12	(, ,	USPAT;	2004/08/09 09:44
		carbide)	US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
_	2	((257/253).CCLS.) and (gallium adj	USPAT;	2004/08/06 14:41
	_	nitride)	US-PGPUB;	2001,00,00 11111
		, ,	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	4	(((257/253).CCLS.) and (silicon adj	USPAT;	2004/08/06 14:37
		carbide)) and passivation	US-PGPUB;	
i			EPO; JPO;	
			DERWENT;	
_	508	(73/31.06).CCLS.	IBM_TDB USPAT;	2004/08/06 14:37
-	308	(73/31.00).0013.	USPAT; US-PGPUB;	2004/00/00 14:3/
			EPO; JPO;	
	•		DERWENT;	
			IBM TDB	
-	10	((73/31.06).CCLS.) and (silicon adj	USPAT;	2004/08/06 14:38
		carbide)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	,	//73/31 06\ CCIC \ and /mallian add	IBM_TDB	0004/00/00 14:00
-	1	((73/31.06).CCLS.) and (gallium adj	USPAT; US-PGPUB;	2004/08/06 14:38
		interide)	EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	2	((((73/31.06).CCLS.) and (silicon adj	USPAT;	2004/08/06 14:41
		carbide)) or (((73/31.06).CCLS.) and	US-PGPUB;	
		(gallium adj nitride))) and passivation	EPO; JPO;	
			DERWENT;	
		, , , , , , , , , , , , , , , , , , , ,	IBM_TDB	
-	77	(gas adj sensor) and (hfet or misfet or mesfet or mishfet or (schottky adj diode))	USPAT;	2004/08/09 09:46
		mester of mishier of (schotcky adj diode))	US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	34	((gas adj sensor) and (hfet or misfet or	USPĀT;	2004/08/06 14:41
		mesfet or mishfet or (schottky adj	US-PGPUB;	
		diode))) and (silicon adj carbide)	EPO; JPO;	
			DERWENT;	
1	_	//	IBM_TDB	2004/00/05
-	7	((gas adj sensor) and (hfet or misfet or mesfet or mishfet or (schottky adj	USPAT;	2004/08/06 14:41
		mesiet or mishiet or (schottky adj diode))) and (gallium adj nitride)	US-PGPUB; EPO; JPO;	
		aroae, , , and (garrium au) mittrue,	DERWENT;	
			IBM TDB	·
[_	14	((((gas adj sensor) and (hfet or misfet or	USPĀT;	2004/08/06 14:43
		mesfet or mishfet or (schottky adj	US-PGPUB;	
[diode))) and (silicon adj carbide)) or	EPO; JPO;	
		(((gas adj sensor) and (hfet or misfet or	DERWENT;	
		mesfet or mishfet or (schottky adj	IBM_TDB	
]		diode))) and (gallium adj nitride))) and		
_	9	passivation ("4862197" "4984446" "5236569"	USPAT	2004/08/06 14:46
	9	"5434551" "5447618" "5545300"	OSERI	2004/00/00 14:46
		"5787866" "5976335" "5976350").PN.		
-	1	6051854.URPN.	USPAT	2004/08/06 14:47
-	4	("5216249" "5285084" "5362975"	USPAT	2004/08/06 14:49
		"5493131").PN.		
-	4	5656827.URPN.	USPAT	2004/08/06 14:51
-	16	4158807.URPN.	USPAT	2004/08/06 14:52

-	6	("5424227" "5990531" "6298079"	USPAT	2004/08/06 15:46
_	0	"6316793" "6479843" "6486502").PN. 6690042.URPN.	USPAT	2004/08/06 15:49
	11	("4007624" "4244918" "4324218"	USPAT	2004/08/06 15:50
	11	"4351182" "4453126" "4706493"	OSIMI	2001/00/00 13:30
		"4931851" "5250170" "5296196"		
		"5298223" "5431883").PN.		
_	21	5698771.URPN.	USPAT	2004/08/06 15:59
_	30	("4777019" "4778769" "4877582"	USPAT	2004/08/06 16:04
		"4894339" "5039390" "5219577"		
		"5408106" "5420746" "5543351"		
		"5571376" "5576563" "5646420"		
		"5653939" "5747839" "5828076"	ĺ	
		"5844834" "5892252" "5900728"		
		"5900729" "5922537" "5923046"		
		"5989947" "5997958" "6057556"	<u> </u>	
		"6066265" "6103868" "6121075"	ĺ	
	24	"6159620" "6211530" "6483125").PN. ("4777019" "4778769" "4877582"	USPAT	2004/08/06 16:56
1 -	24	"4894339" "5039390" "5219577"	USPAI	2004/08/08 18:38
		"5420746" "5576563" "5646420"		
		"5653939" "5747839" "5844834"		
		"5892252" "5899734" "5900728"		
		"5900729" "5922537" "5989947"		
		"5997958" "6057556" "6066265"		
		"6103868" "6121075" "6159620").PN.		
-	18	("4126532" "4343768" "4457161"	USPAT	2004/08/06 16:57
		"4928513" "5248385" "5618496"		
1		"5698771" "5915194" "6027954"		
		"6109094" "6161421" "6165874"		
		"6291838" "6297138" "6298710"		
		"6378355" "6461944" "6488771"		
1		"2001/0015170" "2001/0032493"		
	7	"2002/0019117" "2002/0020853").PN.	HCDAD	2004/08/06 17-00
-	7	("4982243" "5002899" "5086014" "5132749" "5144380" "5173761"	USPAT	2004/08/06 17:00
		"5252294").PN.		
_	7	("4982243" "5002899" "5086014"	USPAT	2004/08/06 17:00
		"5132749" "5144380" "5173761"	002	2001,00,00 2,100
	i	"5252294").PN.		
_	12	5362975.URPN.	USPAT	2004/08/06 17:01
-	14	("3597270" "3645785" "3660154"	USPAT	2004/08/06 17:02
		"4622736" "5270252" "5362975"		
	•	"5399883" "5442200" "5612232"		
		"5635412" "5656827" "5929523"		
	_	"6027954" "6109094").PN.		0004/00/00 = 5
-	2	6291838.URPN.	USPAT	2004/08/06 17:03
-	29		USPAT;	2004/08/06 17:05
1	1	flip\$1chip or (flip adj chip))	US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
_	9	((438/49).CCLS.) and ((silicon adj	USPAT;	2004/08/09 09:45
		carbide) or (gallium adj nitride))	US-PGPUB;	2001,00,00,00,00.40
			EPO; JPO;	
			DERWENT;	
1			IBM TDB	
_	6	(438/49.ccls.) and (hfet or misfet or	USPAT;	2004/08/09 09:47
		mesfet or mishfet or (schottky adj diode))	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	0	mishfet and (gas adj sensor)	USPAT;	2004/08/09 14:55
			US-PGPUB;	
	İ		EPO; JPO;	
			DERWENT;	
	l .		IBM_TDB	

_	22	encapsulation and gate and (gas adj	USPAT;	2004/08/09 14:55
		sensor)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	339	((257/253) or (438/49)).CCLS.	USPAT;	2004/08/09 15:12
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	10	(((257/253) or (438/49)).CCLS.) and	USPAT;	2004/08/09 15:13
:		lanthanum	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	24	72/21 06 1	IBM_TDB	2004/00/00 15:12
_	24	73/31.06 and lanthanum	USPAT;	2004/08/09 15:13
			US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	6	("3951603" "4454954" "4988970"	USPAT	2004/08/09 15:17
		"5306411" "5397541" "5582710").PN.	001111	2004,00,05 13.11